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Photoelectric Sensors with Separate Digital Amplifiers (Laser-type Amplifier Units) E3C-LDA Series

- All three beam types provide ample long-distance detection of 1,000 mm for Diffuse Reflective Models.
- Coaxial Retroreflective Models provide detection performance equivalent to through-beam sensors, simplifying Sensor installation.
- · Industry-first variable focal point and optical axis alignment mechanisms. Optimize for workpieces and improve inspection quality.
- Drive the laser with an Amplifier the same size as a Digital Fiber Amplifier.



Ordering Information

Sensor Heads

Sensing method	Focus	Model number	Remarks
Diffuse reflective	Spot	E3C-LD11	Mounting a Beam Unit (sold separately) allows the use of line and area beams.
	Line	E3C-LD21	This model number is for the set consisting of the E39-P11 mounted to the E3C-LD11.
	Area	E3C-LD31	This model number is for the set consisting of the E39-P21 mounted to the E3C-LD11.
Coaxial retroreflective (with MSR)	Spot (variable)	E3C-LR11 (See note.)	Mounting a Beam Unit (sold separately) allows the use of line and area beams.
	Spot (2.0-mm fixed dia.)	E3C-LR12 (See note.)	

Note: Select a reflector (sold separately) according to the application.

■ Amplifier Units

Amplifier Units with Cables

Item		Appearance	Functions	Model	
				NPN output	PNP output
Advanced models	Twin-output models		Area output, self-diagnosis, differential operation	E3C-LDA11	E3C-LDA41
	External-input models		Remote setting, counter, dif- ferential operation	E3C-LDA21	E3C-LDA51
	ATC function		ATC (Active Threshold Con- trol)	E3C-LDA11AT	E3C-LDA41AT
	Analog output		Analog output	E3C-LDA11AN	E3C-LDA41AN

Amplifier Units with Connectors

Item		Appearance	Functions	Model		
				NPN output	PNP output	
Advanced models	Twin-output models		Area output, self-diagnosis, differential operation	E3C-LDA6	E3C-LDA8	
	External-input models		Remote setting, counter, dif- ferential operation	E3C-LDA7	E3C-LDA9	
	ATC function		ATC (Active Threshold Con- trol)	E3C-LDA6AT	E3C-LDA8AT	

Amplifier Unit Connectors (Order Separately)

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ltem	Appearance	Cable length	No. of con- ductors	Model
Master Connec- tor		2 m	4	E3X-CN21
Slave Connector	1		2	E3X-CN22

Mobile Console (Order Separately)

Appearance	Model	Remarks
	E3X-MC11-SV2 (model number of set) (See notes 1 and 2.)	Mobile Console with Head, Cable, and AC adapter provided as accessories
J	E3X-MC11-C1-S	Mobile Console
A	E3X-MC11-H1	Head
	E39-Z12-1	Cable (1.5 m)

Note 1. Use the E3X-MC11-SV2 Mobile Console for the E3C-LDA-series Amplifier Units. Other Mobile Consoles cannot be used.

 The E3X-MC11-SV2 is an upgraded version of the E3X-MC11-S, to which a corresponding Sensor Head is added. (The E3X-MC11-SV2 and E3X-MC11-S are compatible.)

Specifications

■ Ratings/Characteristics Sensor Heads

■ Accessories (Order Separately) Beam Units

Applicable Sensor Head	Appearance	Focus	Model
E3C-LD11		Line	E39-P11
		Area	E39-P21
E3C-LR11		Line	E39-P31
		Area	E39-P41

Reflectors

Туре	Appearance	Model
Standard Effective area: 23×23 mm		E39-R12
Standard Effective area: 7×7 mm		E39-R13
Short-distance transparent detection Effective area: 23×23 mm	- <u></u>	E39-R14
Sheet (cuttable) Effective area: 195 \times 22 mm		E39-RS4
Sheet (cuttable) Effective area: 108 × 46 mm		E39-RS5

Diffuse reflective Coaxial retroreflective (with MSR)							
E3C-LD11	E3C-LD21	E3C-LD31	E3C-LR11	E3C-LR11 + E39- P31	E3C-LR11 + E39- P41	E3C-LR12	
Red semiconduc	Red semiconductor laser diode (650 nm), 2.5 mW max. (JIS standard: Class 2, FDA standard: Class II) s						
					7 m 5 m 2 m (See note 2.)		
0.8 mm max. (at distances up to 300 mm)	33 mm (at 150 mm)	33 × 15 mm (at 150 mm)	0.8 mm max. (at distances up to 1,000 mm)	28 mm (at 150 mm)	28 × 16 mm (at 150 mm)	2.0 mm dia. (at distances up to 1,000 mm)	
Variable focal po	oint mechanism (beam size adjust	ment) (See note	4.), optical axis adjusti	nent mechanism (axis	adjustment)	
LDON indicator:	Green; Operatio	n indicator: Oran	ge				
3,000 lx (incand	escent lamp)						
Operating: -10°	C to 55°C; Storag	ge: -25°C to 70°C	C (with no icing o	r condensation)			
Operating/storag	ge: 35% to 85% (with no condensa	ation)				
10 to 150 Hz wit	10 to 150 Hz with double amplitude of 0.7 mm, in X, Y, and Z directions for 80 min each						
IEC 60529: IP40)						
Case and cover: ABS Case and cover: ABS Front surface filter: Acrylic resin Front surface filter: Glass							
Approx. 85 g	Approx. 85 g Approx. 100 g						
	E3C-LD11 Red semiconduc High-resolution Standard mode: Super-high-spee (See note 1.) 0.8 mm max. (at distances up to 300 mm) Variable focal po LDON indicator: 3,000 lx (incand Operating: -10° Operating/storag 10 to 150 Hz wit IEC 60529: IP40 Case and cover Front surface filt	E3C-LD11 E3C-LD21 Red semiconductor laser diode (i High-resolution mode: 30 to 1,00 Standard mode: 30 to 700 mm Super-high-speed mode: 30 to 29 (See note 1.) 0.8 mm max. (at distances up to 300 mm) Variable focal point mechanism (i LDON indicator: Green; Operation 3,000 lx (incandescent lamp) Operating: -10°C to 55°C; Storage Operating/storage: 35% to 85% (i 10 to 150 Hz with double amplitu IEC 60529: IP40 Case and cover: ABS Front surface filter:	E3C-LD11 E3C-LD21 E3C-LD31 Red semiconductor laser diode (650 nm), 2.5 mW High-resolution mode: 30 to 1,000 mm Standard mode: 30 to 700 mm Super-high-speed mode: 30 to 250 mm (See note 1.) 0.8 mm max. (at distances up to 300 mm) 33 mm (at 150 mm) 33 × 15 mm (at 150 mm) Variable focal point mechanism (beam size adjust LDON indicator: Green; Operation indicator: Oran 3,000 lx (incandescent lamp) Operating: -10°C to 55°C; Storage: -25°C to 70°C Operating: -10°C to 55°C; Storage: -25°C to 70°C Operating/storage: 35% to 85% (with no condensa 10 to 150 Hz with double amplitude of 0.7 mm, in IEC 60529: IP40 Case and cover: ABS Front surface filter:	E3C-LD11 E3C-LD21 E3C-LD31 E3C-LR11 Red semiconductor laser diode (650 nm), 2.5 mW max. (JIS stand High-resolution mode: 30 to 1,000 mm 5 m 5 m 2 year high-speed mode: 30 to 250 mm (See note 1.) 7 m 5 m 2 year m (See note 1.) 7 m 5 m 2 year m (See note 1.) 0.8 mm max. (at distances up to 300 mm) 33 mm (at 150 mm) 33 × 15 mm (at 150 mm) 0.8 mm max. (at distances up to 300 mm) 0.8 mm max. (at distances up to 300 mm) Variable focal point mechanism (beam size adjustment) (See note LDON indicator: Green; Operation indicator: Orange 3,000 lx (incandescent lamp) 00 perating: -10°C to 55°C; Storage: -25°C to 70°C (with no icing or 0 perating/storage: 35% to 85% (with no condensation) 10 to 150 Hz with double amplitude of 0.7 mm, in X, Y, and Z direct IEC 60529: IP40 Case and cover: ABS Front surface filter: Acrylic resin	E3C-LD11 E3C-LD21 E3C-LD31 E3C-LR11 E3C-LR11 E3C-LR11 + E39- P31 Red semiconductor laser diode (650 nm), 2.5 mW max. (JIS standard: Class 2, FDA star High-resolution mode: 30 to 1,000 mm Standard mode: 30 to 700 mm Super-high-speed mode: 30 to 250 mm (See note 1.) 7 m 2 m (See note 2.) 1,700 mm, 1,300 mm 700 mm (See note 2.) 0.8 mm max. (at distances up to 300 mm) 33 mm (at 150 mm) 33 × 15 mm (at 150 mm) 0.8 mm max. (at distances up to 1,000 mm) 28 mm (at 150 mm) Variable focal point mechanism (beam size adjustment) (See note 4.), optical axis adjustr LDON indicator: Green; Operation indicator: Orange 28 mm (at 150 mm) 3,000 lx (incandescent lamp) Operating: -10°C to 55°C; Storage: -25°C to 70°C (with no icing or condensation) 0perating: -10°C to 55°C; Storage: -25°C to 70°C (with no icing or condensation) 0perating/storage: 35% to 85% (with no condensation) 10 to 150 Hz with double amplitude of 0.7 mm, in X, Y, and Z directions for 80 min each IEC 60529: IP40 Case and cover: ABS Front surface filter: Case and cover: ABS Front surface filter:	E3C-LD11E3C-LD21E3C-LD31E3C-LD31E3C-LR11E3C-LR11E3C-LR11 + E39- P31E3C-LR11 + E39- P41Red semiconductor laser diode (650 nm), 2.5 mW max. (JIS standard: Class 2, FDA standard: Class II)High-resolution mode: 30 to 1,000 mm Standard mode: 30 to 700 mm7 m 5 m 2 m (See note 1.)1,700 mm, 700 mm (See note 2.)900 mm 700 mm (See note 2.)0.8 mm max. (at distances up to 300 mm)33 mm (at 150 mm)33 × 15 mm (at 150 mm)133 × 15 mm (at (at distances up to 1,000 mm)28 mm (at 150 mm)28 × 16 mm (at 150 mm)Variable focal point mechanism (beam size adjustment) (See note 4.), optical axis adjustment mechanism (axis LDON indicator: Green; Operation indicator: Orange28 mm (at 150 mm)28 × 16 mm (at 150 mm)3,000 lx (incandescent lamp)Operating: -10°C to 55°C; Storage: -25°C to 70°C (with no icing or condensation)00Operating/storage: 35% to 85% (with no condensation)0.7 mm, in X, Y, and Z directions for 80 min each1IEC 60529: IP40Case and cover: Front surface filter:ABS Front surface filter:Case and cover: Glass	

Note 1. Values are sensed for white paper.

2 These values apply when a E39-R12 Reflector is used. The MSR function is built-in. The reflected light from the object being measured may affect the sensing accuracy, so adjust the threshold value before use.

3. The beam radius is the value for the middle measurement distance and indicates a typical value for the middle sensing distance. The radius is defined by light intensity of 1/e² (13.5%) of the central light intensity. Light will extend beyond the main beam and may be affected by conditions surrounding the object being measured.

The E3C-LR12 has a fixed beam size (the focus point cannot be changed).

E3C-LDA Series Photoelectric Sensors with Separate Digital Amplifiers (Laser-type Amplifier Units)

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Amplifier Units

		Туре	External-in	put models	Twin-outp	ut models	ATC-outp	out models	Analog-output models		
	Model NPN	l output	E3C-LDA21	E3C-LDA7	E3C-LDA11	E3C-LDA6	E3C- LDA11AT	E3C-LDA6AT	E3C-LDA11AN		
lte	Item PNP output		E3C-LDA51	E3C-LDA9	E3C-LDA41	E3C-LDA8	E3C- LDA41AT	E3C-LDA8AT	E3C-LDA41AN		
Supply v	voltage		12 to 24 VDC	±10%, ripple	(p-p) 10% max	•					
Power c	consumption		1,080 mW ma	x. (current cor	sumption: 45	mA max. at po	ower supply volt	tage of 24 VDC)			
Con- trol out-	ON/OFF out	tput			26.4 VDC max esidual voltage		depends on mo	odel) open collec	tor		
Put Analog output		ut							Control output Voltage output: 1 to 5 VDC (con- nected load 10 kΩ min.) Temperature characteristics 0.3% F.S./°C Response time/Repeat accuracy Super-high-speed mode: 100 μs 4.0% F.S. High-speed mode: 250 μs/4.0% F.S. Standard mode: 1 ms/2.0% F.S. High-resolution mode: 4 ms/2.09		
Re- sponse	Super-high- mode	speed	80 µs for oper set	ation and re-	100 µs for op	eration and re	set		1		
time	High-speed	mode	250 µs for ope	eration and res	set						
	Standard me	ode	1 ms for opera	ation and rese	t						
	High-resolut mode	tion	4 ms for opera	4 ms for operation and reset							
Func- tions	Differential of tion	detec-	Switchable between single edge and double edge detection mode. Single edge: Can be set to 250 μs, 500 μs, 1 ms, 10 ms, or 100 ms. Double edge: Can be set to 500 μs, 1 ms, 2 ms, 20 ms, or 200 ms.								
	Timer function	on	Select from OFF-delay, ON-delay, or one-shot timer. 1 ms to 5 s (1 to 20 ms set in 1-ms increments, 20 to 200 ms set in 10-ms increments, 200 ms to 1 s set in 100-ms increments, and 1 to 5 s set in 1-s increments)								
	Zero-reset		Negative values can be displayed.								
	Initial reset		Settings can b	be returned to	defaults as req	uired.					
	Mutual interprevention	ference	Possible for up to 10 Units. (See note.)								
	Counter		Switchable be counter and d Set count: 0 to	own counter.							
	I/O settings		External input lect from teac tuning, zero re or counter res	hing, power set, light OFF,	Output setting channel 2 out put, or self-dia	put, area out-	Output setting channel 2 outp self-diagnosis output.)	out, area output,	Analog output setting (Offset vol age can be adjusted.)		
Digital d	lisplay		Select from di	gital incident l	evel + threshol	d or six other	patterns.				
Display	orientation		0		eversed displa	, i					
Ambient	t temperature	range	Operating: Groups of 1 to 2 Amplifiers: -25°C to 55°C Groups of 3 to 10 Amplifiers: -25°C to 50°C Groups of 11 to 16 Amplifiers: -25°C to 45°C Storage: -30°C to 70°C (with no icing)								
Ambient	t humidity ran	ige	Operating and	d storage: 35%	5 to 85% (with 1	no condensati	on)				
Insulatic	on resistance		20 MΩ at 500 VDC								
Dielectri	ic strength		1,000 VAC at 50/60 Hz for 1 min.								
Vibratio	n resistance		Destruction: 10 to 150 Hz, 0.7-mm double amplitude for 80 min each in X, Y, and Z directions								
	esistance				es each in X,	Y, Z direction	ons				
Degree	of protection		IP50 (IEC 605	529)							
	tion method (packed state)	Prewired cable or wire-reducing connector With prewired cable: Approx. 100 g								
				•	or: Approx. 55	g					
Materi- als	Case		<u> </u>	terephthalate (РВТ)						
	Cover		Polycarbonate	;							

Note: Communications are disabled if super-high-speed mode is selected, and the mutual interference prevention function and the communications function for the Mobile Console will not function.

Dimensions

Sensor Head



This document provides information mainly for selecting suitable models. Please read the Instruction Sheet carefully for information that the user must understand and accept before purchase, including information on warranty, limitations of liability, and precautions.

ALL DIMENSIONS SHOWN ARE IN MILLIMETERS. To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.

Cat. No. E338-E1-04 In the interest of product improvement, specifications are subject to change without notice.

OMRON Corporation

Industrial Automation Company

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